

Electronic Supplementary Information (ESI)

Novel Flux Coating Method for Fabrication of Layer of Visible-Light-Responsive Ta₃N₅ Crystals on Tantalum Substrate

Sayaka Suzuki,^a Hajime Wagata,^a Mugi Komatsu,^a Tsutomu Minegishi,^b Kazunari Domen,^b Shuji Oishi^a and Katsuya Teshima^{*,a,c}

^aDepartment of Environmental Science and Technology, Faculty of Engineering, Shinshu University, 4-17-1 Wakasato, Nagano 380-8553, Japan

^bDepartment of Chemical System Engineering, School of Engineering, The University of Tokyo, 7-3-1 Hongo, Bunkyo-ku, Tokyo 113-8656, Japan

^cCenter for Energy and Environmental Science, Shinshu University, 4-17-1 Wakasato, Nagano 380-8553, Japan

E-mail: teshima@shinshu-u.ac.jp

**Corresponding Author: Katsuya Teshima*

Materials and reagents

To fabricate the Ta₃N₅ crystal layers, Ta foil (99.95 %, Nilaco Corporation), NaNO₃ (99.0 %, Wako Pure Industries, Ltd.), NaCl (99.5 %, Wako Pure Industries, Ltd.), and Na₂CO₃ (99.8 %, Wako Pure Industries, Ltd.) were used. The solution-coated substrates were heated using NH₃ (99.9995 %, Sumitomo Seika Chemicals Co., Ltd.) and N₂ (99.9995 %, Taiyo Nippon Sanso Corporation) gases. For the modification using a cocatalyst, Co(NO₃)₂·6H₂O (99.5 %, Wako Pure Industries, Ltd.), K₂HPO₄ (99.0 %, Kanto Chemicals), KH₂PO₄ (99.5 %, Kanto Chemicals), Na₂SO₄ (99.0 %, Wako Pure Industries, Ltd.), and NaOH (97.0 %, Wako Pure Industries, Ltd.) were used. All the chemicals were used as-purchased without further purification.

Fabrication of samples for UV-vis spectral measurements

We could not measure the Kubelka-Munk spectrum for the Ta₃N₅ crystal layers on the Ta substrate with accuracy, because of absorption by the Ta substrate. Therefore, we fabricated the Ta₃N₅ crystal layers on a silica-glass substrate, and subsequently measured their light absorption properties in the transmission mode.

First, a layer of Ta was deposited on the silica-glass substrate (20 × 20 × 0.5 mm) by sputtering (Kenix Co., Ltd., RF sputter system, KXS-410B) using a Ta target (99.99 %, High Purity Chemicals). The deposited Ta layer had a thickness of approximately 60 nm. The subsequent procedures for the fabrication of the Ta₃N₅ crystal layers were basically the same as those of the fabrication of the layers on the Ta substrates. The Ta layer was dry-cleaned and hydrophilized by being irradiated under vacuum-ultraviolet light ($\lambda = 172$ nm). Next, 13.3 μ L of the NaCl-Na₂CO₃ aqueous solution was placed on the Ta layer. Because 5 μ L of the solution was used for the Ta substrates, which had dimensions of 10 × 15 mm, the amount of solution used was increased to 13.3 μ L for the silica-glass substrates, which were larger in size (dimensions of 20 × 20 mm). The solution-coated substrates were dried in an electric oven at 100 °C for 30 min. Subsequently, the substrates were heated to 850 °C at a rate of 10 °C·min⁻¹ and held at this temperature for 1 h in an NH₃ flow (100 mL·min⁻¹).

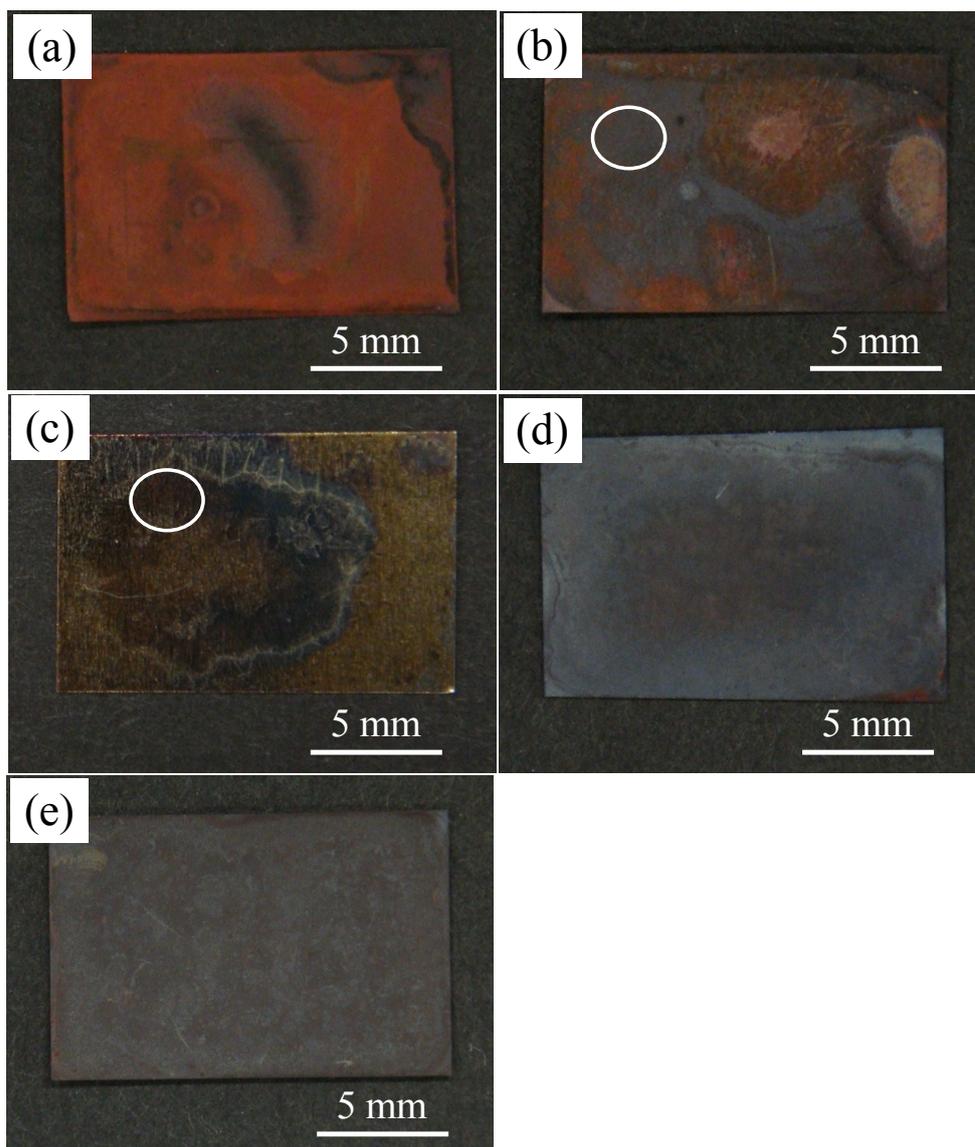


Fig. S1 Digital photographs of the crystal layers fabricated using (a) NaNO_3 (Run No. 1), (b) Na_2CO_3 (Run No. 2), (c) NaCl (Run No. 3), and (d, e) $\text{NaCl-Na}_2\text{CO}_3$ as the fluxes. (d) $10 \mu\text{L}$ (Run No. 4) and (e) $5 \mu\text{L}$ (Run No. 5) of an aqueous $\text{NaCl-Na}_2\text{CO}_3$ solution were used as the fluxes.

Table S1 Crystallite sizes of the crystal layers fabricated using the various fluxes.

run no.	flux (molar ratio)	amount of coating / μL	crystallite size / nm
1	NaNO_3	10	18.3
2	Na_2CO_3	10	18.0
3	NaCl	10	36.6
4	$\text{NaCl-Na}_2\text{CO}_3$ (4 : 1)	10	31.1
5	$\text{NaCl-Na}_2\text{CO}_3$ (4 : 1)	5	36.1

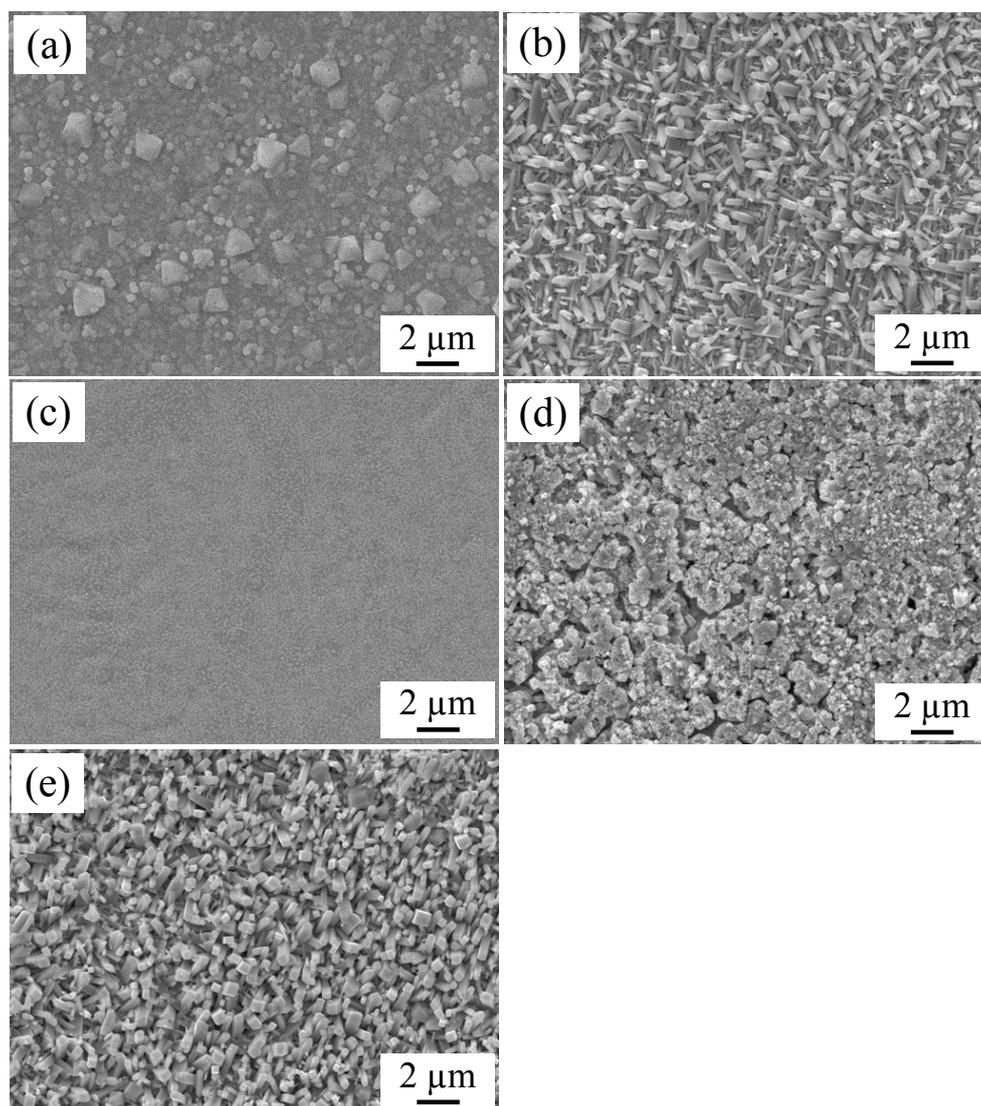


Fig. S2 Low-magnification surface SEM images of the crystal layers fabricated using (a) NaNO_3 (Run No. 1), (b) Na_2CO_3 (Run No. 2), (c) NaCl (Run No. 3), and (d, e) $\text{NaCl-Na}_2\text{CO}_3$ as the fluxes. (d) $10\ \mu\text{L}$ (Run No. 4) and (e) $5\ \mu\text{L}$ (Run No. 5) of an aqueous $\text{NaCl-Na}_2\text{CO}_3$ solution were used as the fluxes.

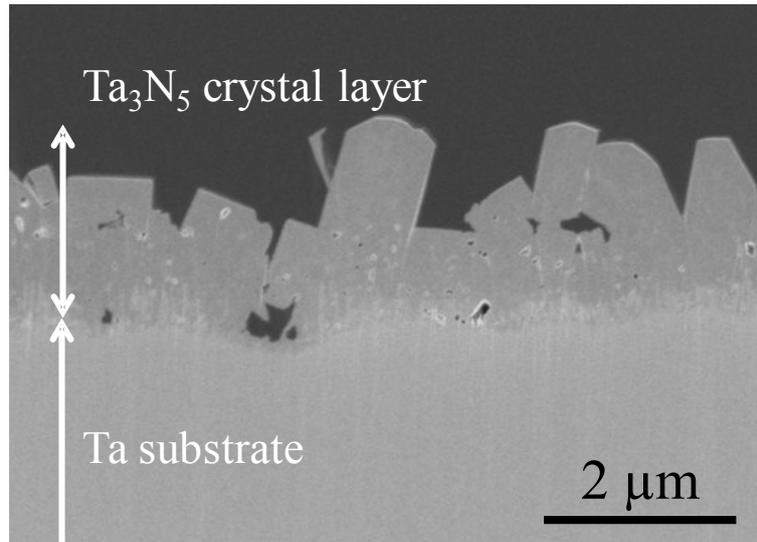


Fig. S3 Cross-sectional SEM image of the crystal layer fabricated using NaCl-Na₂CO₃ as the flux at 850 °C for 1 h (Run No. 5).

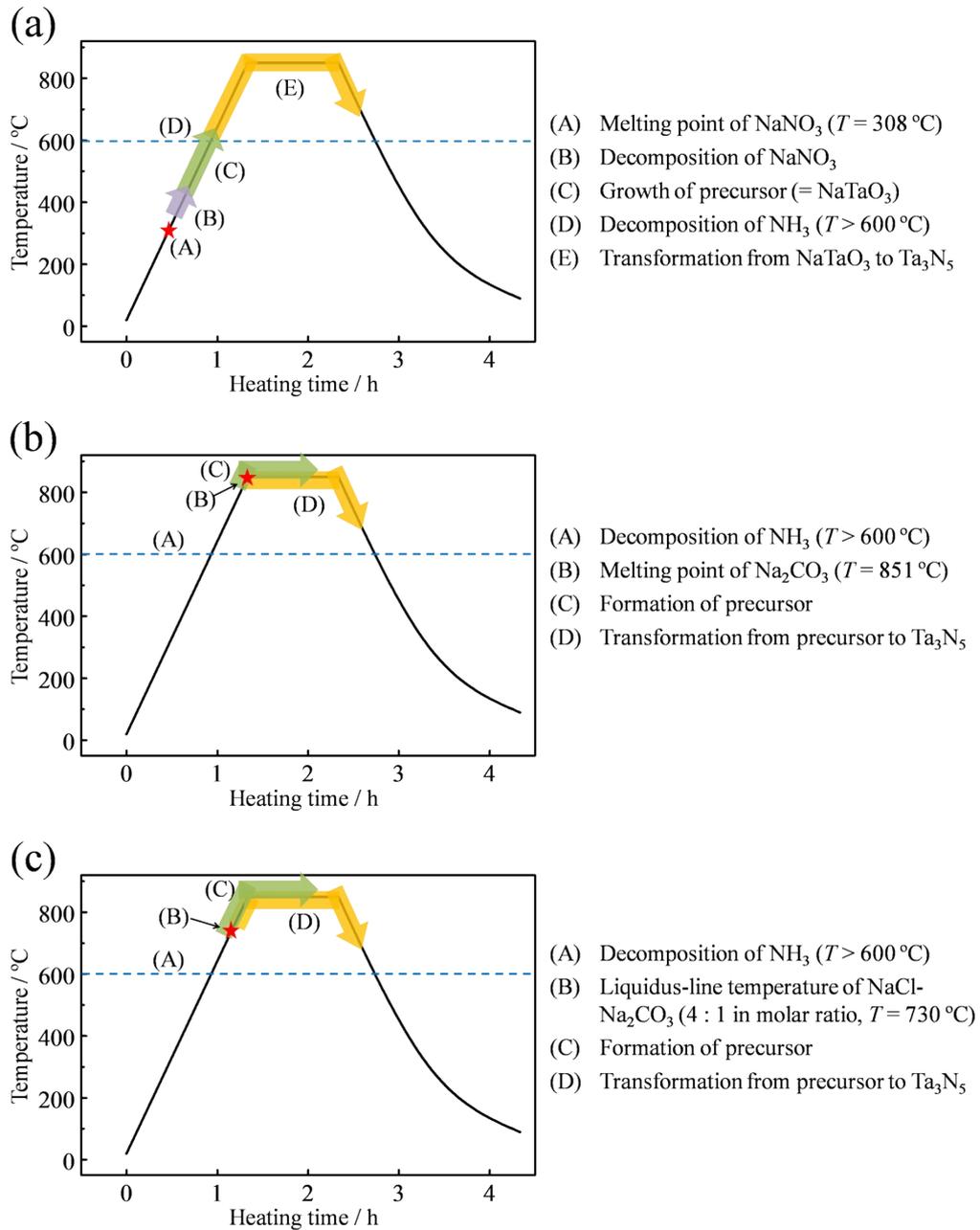


Fig. S4 Illustration of the formation mechanism of Ta_3N_5 crystal layers using (a)

NaNO_3 , (b) Na_2CO_3 , and (c) $\text{NaCl-Na}_2\text{CO}_3$ as the fluxes.

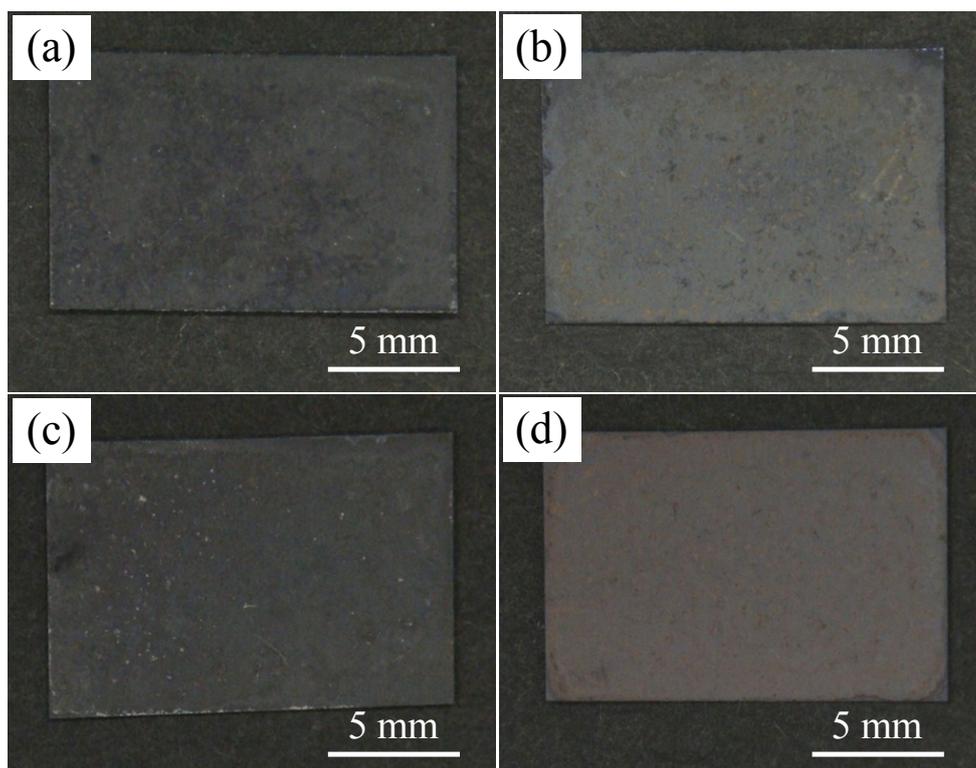


Fig. S5 Digital photographs of the crystal layers fabricated using NaCl-Na₂CO₃ as the flux at different holding temperatures and a holding time of 0 h: (a) 700 °C (Run No. 6), (b) 750 °C (Run No. 7), (c) 800 °C (Run No. 8), and (d) 850 °C (Run No. 9).

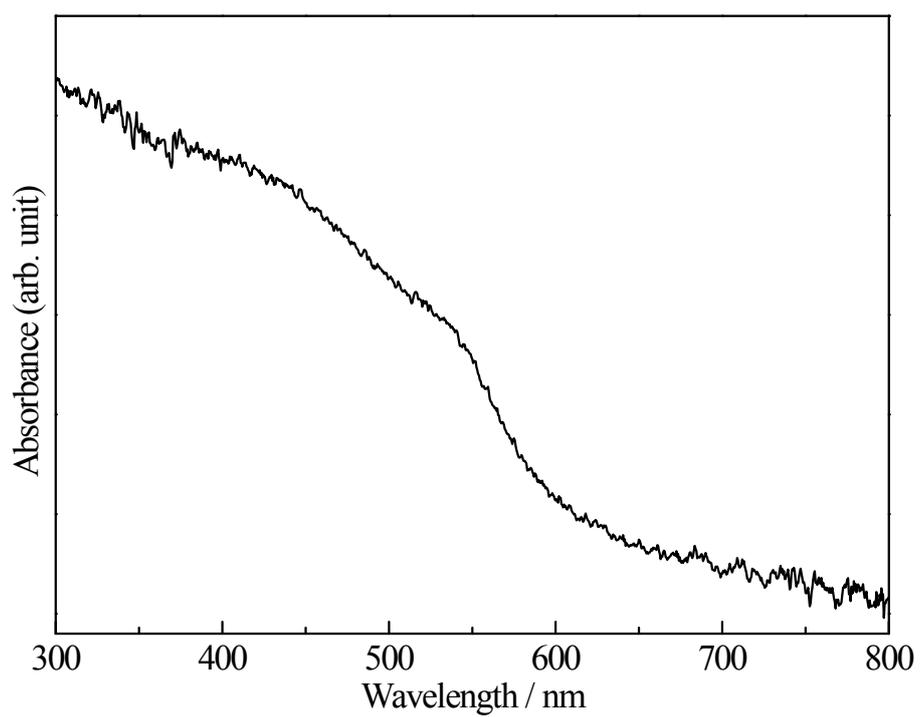


Fig. S6 UV-vis absorption spectrum of the crystal layers fabricated on the silica-glass substrate using NaCl-Na₂CO₃ as the flux at 850 °C for 1 h.